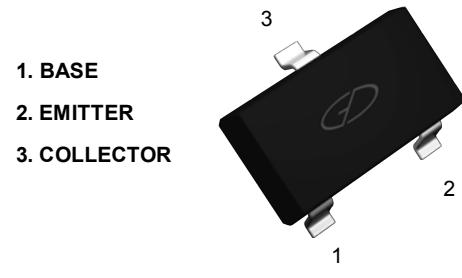


## Features

- High breakdown voltage
- Low collector-emitter saturation voltage



## Absolute Maximum Ratings

( $T_A=25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	Max.	Unit
Collector-Base Voltage	$V_{\text{CBO}}$	-400	V
Collector-Emitter Voltage	$V_{\text{CEO}}$	-400	V
Emitter-Base Voltage	$V_{\text{EBO}}$	-5	V
Collector Current-Continuous	$I_C$	-200	mA
Collector Current-Pulsed	$I_{\text{CM}}$	-300	mA
Collector Power Dissipation	$P_C$	350	mW
Thermal Resistance Junction to Ambient	$R_{\theta\text{JA}}$	357	°C/W
Operation Junction Temperature Range	$T_J$	-55 To +150	°C
Storage Temperature Range	$T_{\text{STG}}$	-55 To +150	°C

## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(\text{BR})\text{CBO}}$	$I_C=-100\mu\text{A}, I_E=0$	-400	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(\text{BR})\text{CEO}}$	$I_C=-1\text{mA}, I_B=0$	-400	-	-	V
Emitter-Base Breakdown Voltage	$V_{(\text{BR})\text{EBO}}$	$I_E=-100\mu\text{A}, I_C=0$	-5	-	-	V
Collector Cut-Off Current	$I_{\text{CBO}}$	$V_{\text{CB}}=-400\text{V}, I_E=0$	-	-	-0.1	$\mu\text{A}$
	$I_{\text{CEO}}$	$V_{\text{CE}}=-400\text{V}, I_B=0$	-	-	-5	$\mu\text{A}$
Emitter Cut-Off Current	$I_{\text{EBO}}$	$V_{\text{EB}}=-4\text{V}, I_C=0$	-	-	-0.1	$\mu\text{A}$
DC Current Gain	$h_{\text{FE}(1)}$	$V_{\text{CE}}=-10\text{V}, I_C=-10\text{mA}$	80	-	300	-
	$h_{\text{FE}(2)}$	$V_{\text{CE}}=-10\text{V}, I_C=-1\text{mA}$	70	-	-	-
	$h_{\text{FE}(3)}$	$V_{\text{CE}}=-10\text{V}, I_C=-100\text{mA}$	40	-	-	-
	$h_{\text{FE}(4)}$	$V_{\text{CE}}=-10\text{V}, I_C=-50\text{mA}$	40	-	-	-
Collector-Emitter Saturation Voltage	$V_{\text{CE}(\text{sat})1}$	$I_C=-10\text{mA}, I_B=-1\text{mA}$	-	-	-0.2	V
	$V_{\text{CE}(\text{sat})2}$	$I_C=-50\text{mA}, I_B=-5\text{mA}$	-	-	-0.3	
Base-Emitter Saturation Voltage	$V_{\text{BE}(\text{sat})}$	$I_C=-10\text{mA}, I_B=-1\text{mA}$	-	-	-0.75	V
Transition Frequency	$f_T$	$V_{\text{CE}}=-20\text{V}, I_C=-10\text{mA}, f=30\text{MHz}$	50	-	-	MHz

### Typical Characteristic Curves

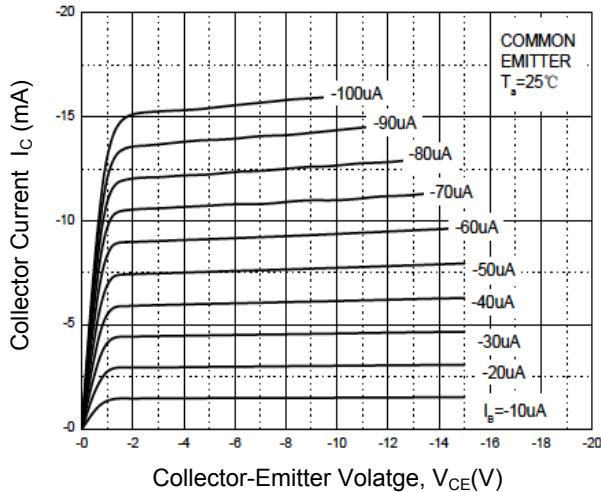


Figure 1. Static Characteristic

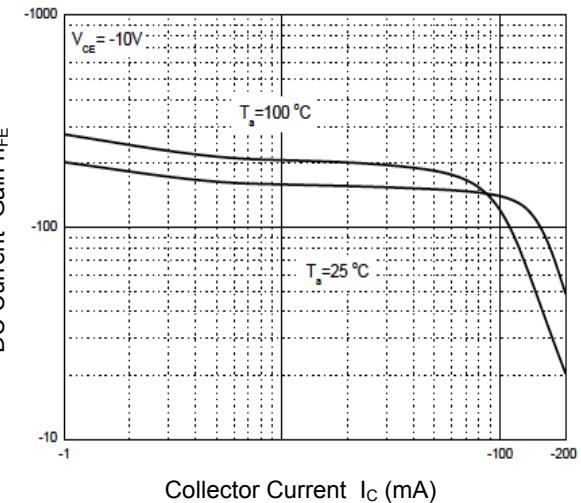


Figure 2. DC Current Gain vs Collector Current

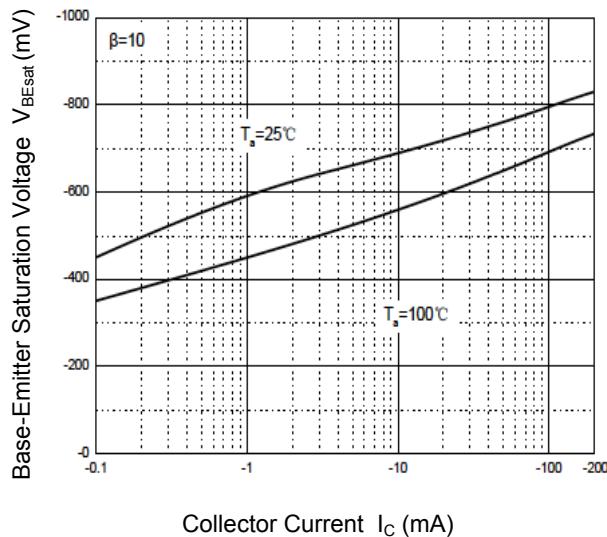


Figure 3 Base-Emitter Saturation Voltage vs.  
 Collector Current

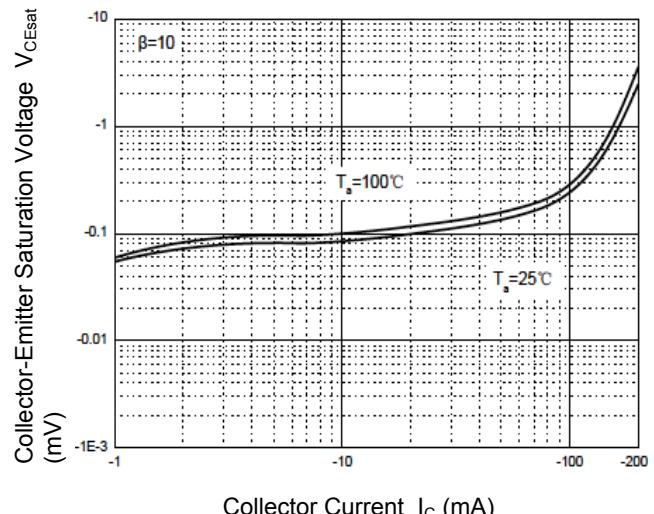


Figure 4. Collector-Emitter Saturation Voltage vs.  
 Collector Current

### Typical Characteristic Curves

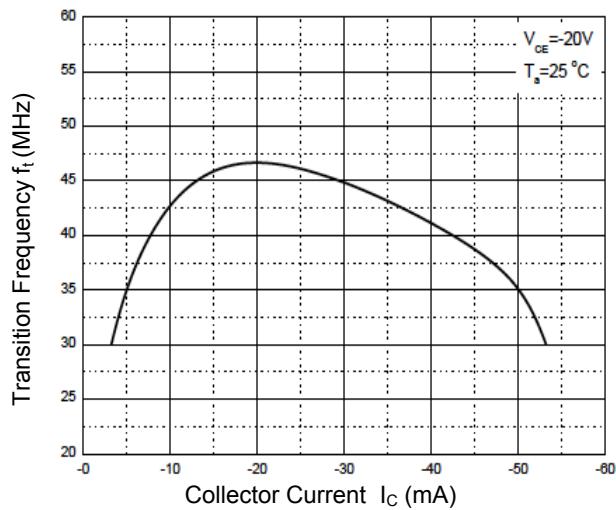


Figure 5. Transition Frequency vs. Collector Current

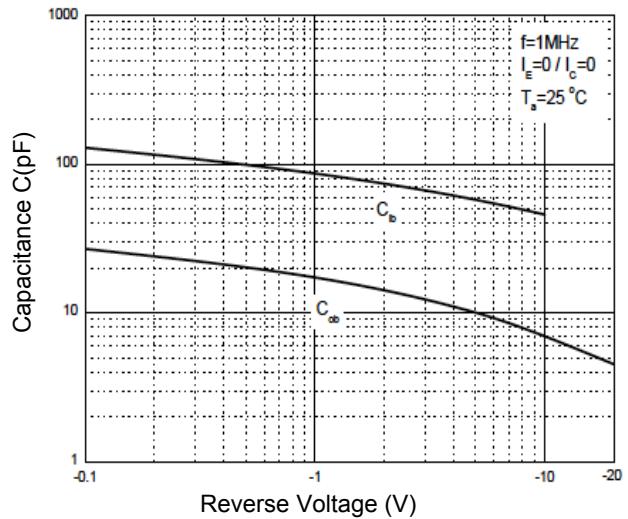


Figure 6. Capacitance Characteristics

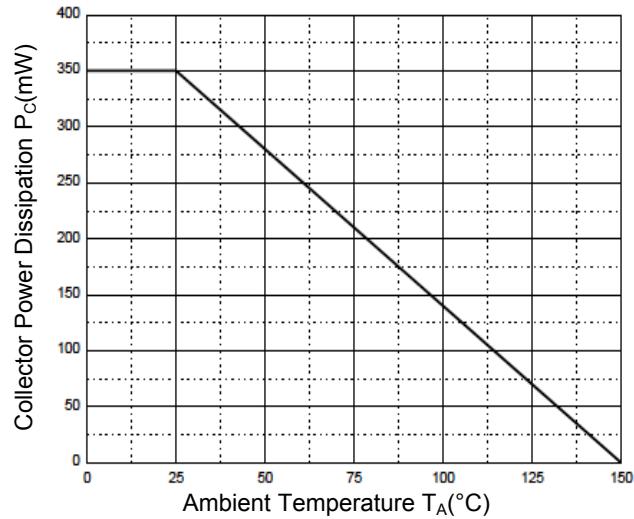
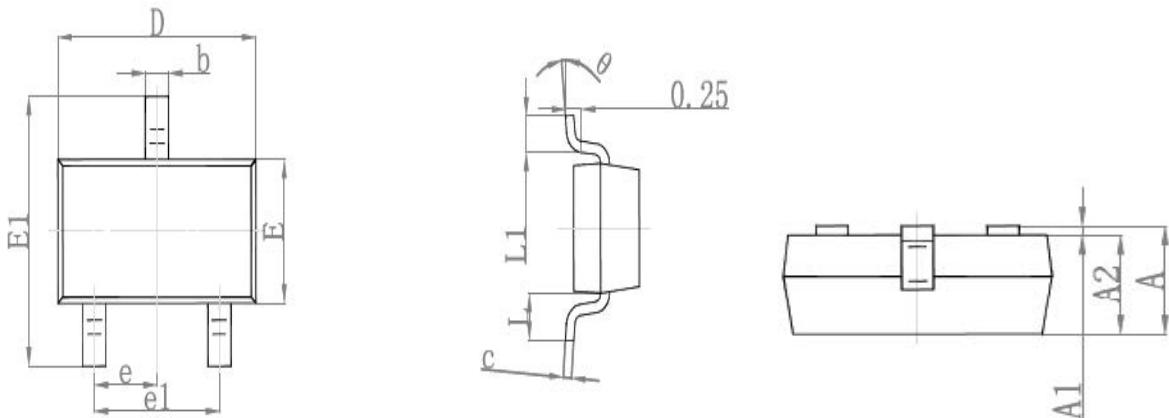


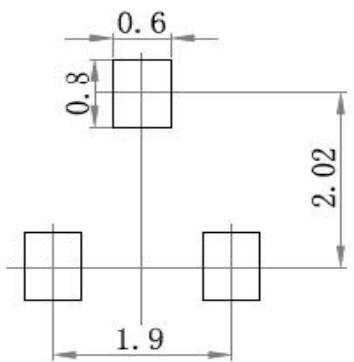
Figure 7. Power Dissipation vs Ambient Temperature

### Package Outline Dimensions (SOT-23)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

### Recommended Pad Layout



Note:  
 1. Controlling dimension: in millimeters.  
 2. General tolerance:  $\pm 0.05\text{mm}$ .  
 3. The pad layout is for reference purposes only.

### Ordering Information

Device	Package	Marking	Quantity	HSF Status
GSMMBTA94	SOT-23	4D	3,000pcs / Reel	RoHS Compliant